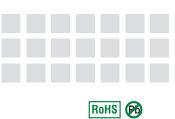
Protection IC Datasheet

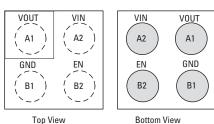
LQ05021QCS4

5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control





Pinout Designation



Pin Description

Pin #	Pin Name	Description
A1	V _{OUT}	Switch output
A2	V _{IN}	Switch input. Supply voltage for IC
B1	GND	Ground
B2	EN	Enable to control the switch. The EN pin has an internal pull-down resistor

Description

The LQ05021QCS4 is an ultimated efficient, 2 A rated integrated load switch with slew rate control. Its outstanding performance in efficiency makes this an ideal solution for applications like IoT, mobile and wearable.

This remarkable device incorporates cutting-edge technology that achieves industry-leading performance in terms of the lowest quiescent current (I_{α}), and shutdown current (I_{sp}). The low I_{α} and I_{sp} solutions empower designers to curtail parasitic leakage current, enhance system efficiency, and extend battery lifespan. The integration of slew rate control within the LQ05021QCS4 serves as a critical enhancement to system reliability, effectively mitigating voltage swings on the bus during switching events. In situations where uncontrolled switches might otherwise generate substantial inrush currents, leading to voltage droop and potential bus reset events, the slew rate control functions to confine inrush current during activation, thereby minimizing the voltage droop. The LQ05021QCS4 load switch device is designed in a chip scale

package of 0.77 mm x 0.77 mm x 0.46 mm with 4 bumps and 0.4 mm pitch and support an extensive input voltage range, enhancing both the operational lifespan and the resilience of the system. Additionally, this single device can serve in various voltage rail applications, streamlining inventory management and lowering operational expenses.

Features and Benefits

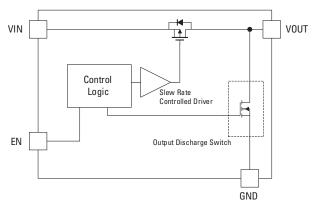
- Ultra-low I_Q: 1 nA Typ @ 5.5 V_{IN}
- Ultra-low I_{SD}: 19 nA Typ @
 5.5 V_{IN}
- Low R_{oN} = 34 mΩ Typ @ 5.5
 V_{IN}
- I_{OUT} max = 2.0 A
- Wide input range: 1.1 V to 5.5 V, 6 Vabs max
- Controlled rise time: 430 µs at 3.3 V_{IN}
- Internal EN pull-down resistor
- Integrated output discharge switch
- Ultra small: 4 bumps in a 0.77 mm x 0.77 mm x 0.46 mm WLCSP

Applications

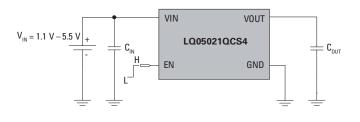
- Mobile devices
- Data storage, SSD
- IoT devices
- Wearables
- Low power subsystems







Typical Applications



Absolute Maximum Rating

Symbol	Par	Min	Max	Unit	
$\rm V_{in'} V_{out'} V_{en}$	Each Pin Volta	-0.3	6	V	
I _{out}	Maximum Contir		2	А	
P _D	Power Dissipa		1	W	
T _{stg}	Storage June	-65	150	°C	
T	Maximum Jur		150	°C	
θ_{JA}	Thermal Resistance, Junctic		110	°C/W	
FCD		Human Body Model, JESD22-A114	6		kV
ESD	Electrostatic Discharge Capability	Charged Device Model, JESD22-C101	2		kV

Note: Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions; extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Recommend Operating Conditions

Symbol	Parameter	Min	Max	Unit
V _{IN}	Supply Voltage	1.1	5.5	V
T _A	Ambient Operating Temperature	-40	85	°C

Note: The device is not guaranteed to function outside of the recommended operating conditions.

Electrical Characteristics (Values are at V_{IN} = 3.3 V and T_A = 25 °C unless otherwise noted.)

Symbol	Parameter	Test Conditions		Min	Тур	Мах	Unit
Basic Operation	on						
V _{IN}	Supply Voltage			1.1		5.5	V
		V _{IN} = V _{EN} =5.5 V,	I _{out} = 0 mA		520		nA
Ι _α	Quiescent Current	V _{IN} = V _{EN} =5.5 V,	$I_{out} = 0 \text{ mA}^1$		1		nA
		V _{IN} = V _{EN} = 5.5 V, I _{OUT} =	0 mA, T _A = 85 °C ¹		12		nA
		EN = Disable, I_{OUT} =	0 mA, V _{IN} = 1.1 V		3		nA
		EN = Disable, I _{OUT} =	0 mA, V _{IN} = 1.8 V		4		nA
		EN = Disable, I _{out} =	0 mA, V _{IN} = 3.3 V		6		nA
I _{SD}	Shutdown Current	EN = Disable, I _{out} =	0 mA, V _{IN} = 4.5 V		9		nA
		EN = Disable, I _{out} =	0 mA, V _{IN} = 5.5 V		19	50	nA
		EN = Disable, I _{out} = 0 mA,	, V _{IN} = 5.5 V, T _A = 55 °C		110		nA
		EN = Disable, I _{out} = 0 mA	a, V _{IN} = 5.5V, T _A = 85 °C		600		nA
			T _A = 25 °C		34	47	mΩ
	On-Resistance	V _{IN} = 5.5 V, I _{OUT} = 500 mA	T _A = 85 °C		40		mΩ
			T _A = 25 °C		42	56	mΩ
R _{on}		$VI_{IN} = 3.3 V$, $I_{OUT} = 500 mA$	T _A = 85 °C		50		mΩ
		V _{IN} = 1.8 V, I _{OUT} = 300 mA	T _A = 25 °C		68		mΩ
		$V_{IN} = 1.2 \text{ V}, I_{OUT} = 100 \text{ mA}$	T _A = 25 °C		125		mΩ
		V _{IN} = 1.1 V, I _{OUT} = 100 mA	T _A = 25 °C		155		mΩ
R _{DSC}	Output Discharge Resistance	E _N = Low , I _{FOR}		70	85	100	Ω
		V _{IN} = 1.1 V - 1.8 V		0.9			V
V _{IH}	EN Input Logic High Voltage	V _{IN} = 1.8 V	- 5.5 V	1.2			V
		V _{IN} = 1.1 V - 1.8 V				0.3	V
V _{IL}	EN Input Logic Low Voltage	V _{IN} = 1.8 V	- 5.5 V			0.4	V
R _{EN}	EN Internal resistance	Internal Pull-down Resistance		7	10.1	13	MΩ
I _{en}	EN Current	E _N = 5.5 V				0.8	μA
Switching Cha	aracteristics ²			1			
t _{don}	Turn-On Delay	D 150.0.0	0.4 5		275		μs
t _R	V _{out} Rise Time	$R_{L} = 150 \ \Omega, \ C_{OUT} = 0.1 \ \mu F$			430		μs
t _{dON}	Turn-On Delay ⁴				245		μs
t _R	V _{out} Rise Time⁴				410		μs
t _{dOFF}	Turn-Off Delay ^{3.4}		0.4 5		0.38		μs
t _F	V _{out} Fall Time ^{3.4}	$R_{L} = 10 \ \Omega, \ C_{OUT} = 0.1 \ \mu F$			1.32		μs
t _{dOFF}	Turn-Off Delay⁴	D = 500 5 6	0.4 5		1.1		μs
t _F	V _{out} Fall Time ^{3.4}	$R_{L} = 500 \Omega$, $C_{OUT} = 0.1 \mu F$			18		μs

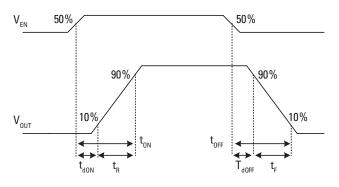
Notes:

1. I_{0} does not include enable pull down current through the pull-down resistor RPD.

2. $t_{ON} = td_{ON} + t_{R'}$, $t_{OFF} = td_{OFF} + t_{F}$ 3. Output discharge path is enabled during off.

4. By design; characterized, not production tested.

Timing Waveforms



Typical Performance Characteristics

180

160

40

20

0

-40

V_{IN} = 1.1V

Figure 1 - On-Resistance vs. Supply Voltage

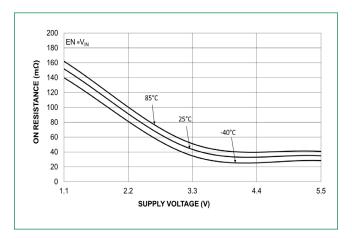


Figure 3 - Quiescent Current vs. Supply Voltage

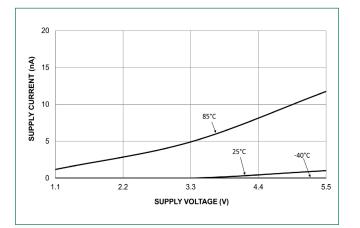


Figure 4 - Quiescent Current vs. Temperature

10

T_J, JUNCTION TEMPERATURE (°C)

V_{IN} = 3.3V

-15

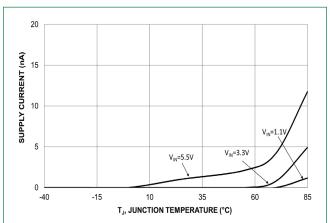


Figure 2 - On-Resistance vs. Temperature

Operating under $I_0 \le 1.5 \text{ A}$

35

V_{IN} = 5.5V

60

 $EN = V_{IN}$

85

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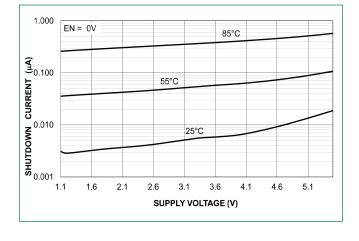


Figure 7 - EN Input Logic High Threshold

-40°C

25°C

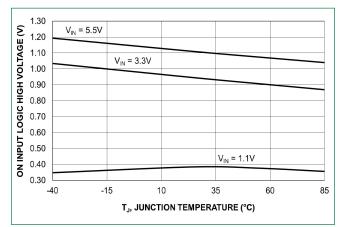
85°C

Figure 5 - Shutdown Current vs. Supply Voltage

1.000 SHUTDOWN CURRENT (µA) 0.000 V_{IN} = 1.1V V_{IN} = 5.5V V_{IN} = 3.3\ 0.001 -15 85 -40 10 35 60 T_J, JUNCTION TEMPERATURE (°C)

Figure 6 - Shutdown Current vs. Temperature









3.1

SUPPLY VOLTAGE (V)

4.1

5.1

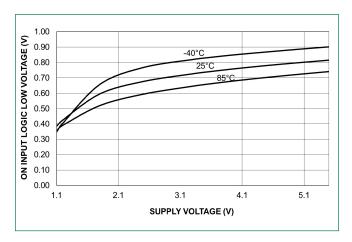
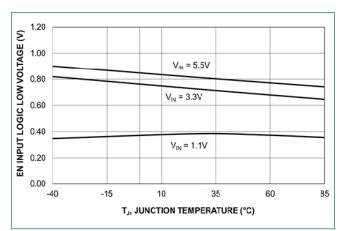


Figure 10 - EN Input Logic Low Threshold Vs. Temperature



1.30

1.20

1.10

1.00

0.90

0.80

0.70

0.60

0.50

1.1

2.1

EN INPUT LOGIC HIGH VOLTAGE (V)

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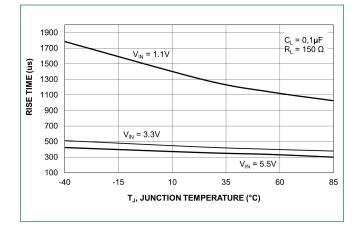


Figure 11 - V_{OUT} Rise Time vs. Temperature

Figure 12 - Turn-On Delay Time vs. Temperature

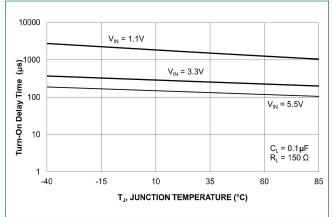


Figure 13 - Pull-down Resistance vs. Temperature

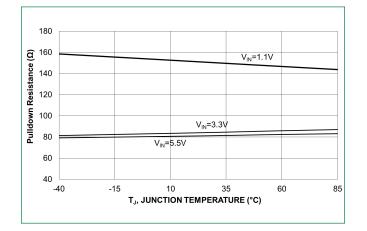


Figure 15 - Turn-On Response V $_{\rm IN}$ = 3.3 V, C $_{\rm IN}$ = 1.0 μ F, C $_{\rm OUT}$ = 0.1 μ F, R $_{\rm L}$ = 150 Ω

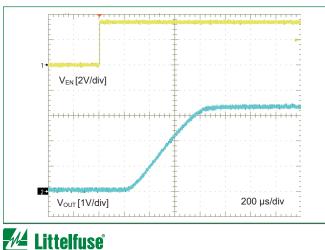


Figure 14 - Enable Input Current vs. Temperature

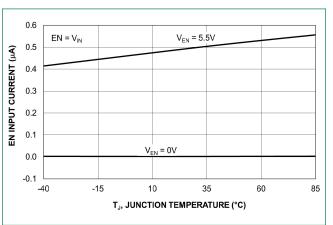
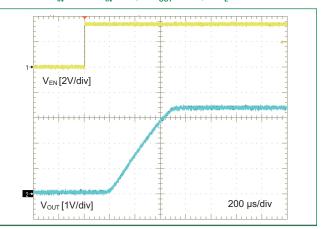
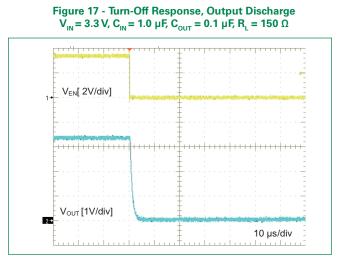


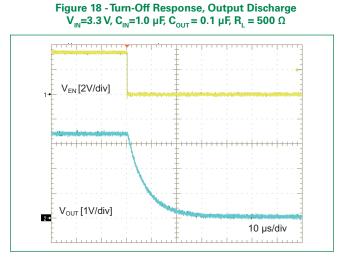
Figure 16 - Turn-On Response V_{IN}=3.3 V, C_{IN}=1.0 \ \mu\text{F}, C_{OUT}=0.1 \ \mu\text{F}, R_{L}=500 \ \Omega



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LQ05021QCS4 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control





Application Information

The LQ05021QCS4 is a highly efficient integrated load switch with a 2 A capacity. It allows a fixed slew rate control to limit inrush current when activated. This device works with a wide input voltage range, from 1.1 V to 5.5 V, and has minimal on-resistance to reduce power loss. When it is off, it has very low leakage current, saving power resources. It is in a chip scale size package at 0.77 mm x 0.76 mm with 4 bumps at a 0.4 mm pitch make it ideal for efficient manufacturing in the space-saving required applications.

Input Capacitor

The proper functioning of the LQ05021QCS4 needs the presence of an input capacitor. Consider using a 1 μ F capacitor positioned near the VIN pin to address voltage fluctuations on the input power rail that may occur as a result of transient inrush current during startup. To reduce the extent of the input voltage drop, suggest to use a higher input capacitor value.

Output Capacitor

It is advisable to employ an output capacitor to minimize voltage undershoot on the output pin during switch-off.

Voltage undershoot may arise due to parasitic inductance from board traces or deliberate load inductances. In the presence of load inductances, utilizing an output capacitor can enhance output voltage stability and overall system reliability. Position the C_{out} capacitor in close proximity to the V_{out} and GND pins.

EN pin

The device can be turned on by setting the EN pin to a high level. Be aware that there is an internal pull-down resistor in EN pin which can pull the primary switch to "off state" as long as no EN signal from an external controller is applied.

Output Discharge Function

The device incorporates an internal discharge N-channel FET switch located at the VOUT pin. When the EN signal switches the primary power FET to an off state, the N-channel switch activates to rapidly discharge the output capacitor.

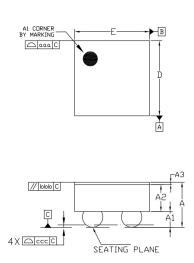
Board Layout

To minimize the impact of parasitic inductance, it is advisable to keep all traces as short as possible. Using wider traces for V_{INV} , V_{OUTV} and GND is recommended to mitigate parasitic effects during dynamic operations and enhance thermal efficiency under high load currents.

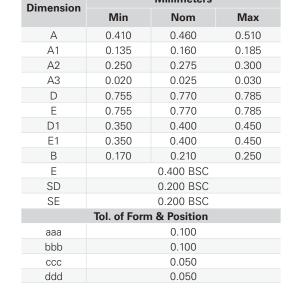


LQ05021QCS4 5 V, 2 A Ultra Low Consumption Load Switch With Slew Rate Control

Dimensions

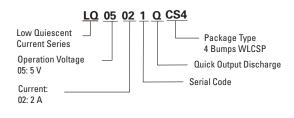


E E 2	1 1	
\bigcirc	\oplus	T A
\bigcirc	\bigcirc	_e B
	Øb Øb	ΒA



Millimeters

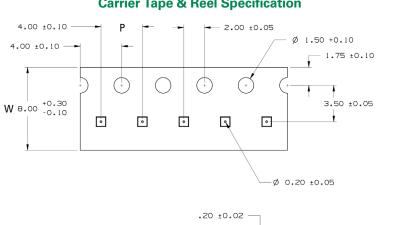
Part Numbering



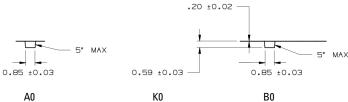
Part Marking

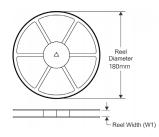


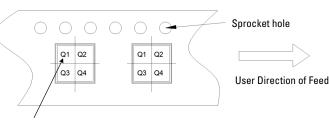
Pin 1 mark B = Device Code XX = Lot Run Code



Carrier Tape & Reel Specification







Quandrant assignments pin 1 orientation Dimensions are in millimeters

Device	Package	Pins	SPQ	Reel Diameter	Reel Width W1	A0	В0	К0	Р	w	Pin1
LQ05021QCS4	4 Bumps WLCSP	4	4000	180	9	0.85	0.85	0.59	4	8	Q1

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